

ISC Silicon NPN Power Transistor

2SD291

DESCRIPTION

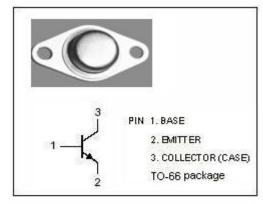
- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR) CEO}= 40V(Min)
- · Collector Power Dissipation-
- : P_C= 18W @T_C= 25℃
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

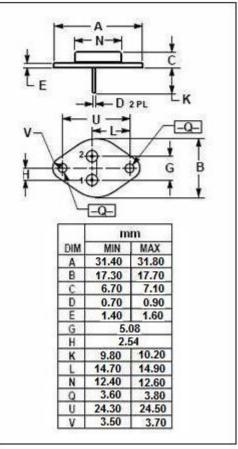


• Designed for use in general purpose amplifier and switching applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|---|---------|------------|
| V_{CBO} | Collector-Base Voltage | 70 | V |
| V _{CEO} | Collector-Emitter Voltage | 40 | V |
| V _{EBO} | Emitter-Base Voltage | 10 | V |
| Ic | Collector Current-Continuous | 3 | А |
| I _{CM} | Collector Current-Peak | 5 | Α |
| I _B | Base Current | 1 | А |
| Pc | Collector Power Dissipation@T _C =25℃ | 18 | W |
| TJ | Junction Temperature 150 | | $^{\circ}$ |
| T _{stg} | Storage Temperature | -65~150 | |







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | MAX | UNIT |
|-----------------------|--------------------------------------|--|-----|-----|------|
| V _{CEO(SUS)} | Collector-Emitter Sustaining Voltage | I _C = 30mA ; I _B = 0 | 40 | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = 2A; I _B = 0.4A | | 2.0 | V |
| V _{BE(on)} | Base-Emitter On Voltage | I _C = 2A; V _{CE} = 4V | | 1.8 | V |
| I _{CBO} | Collector Cutoff Current | V _{CB} = 70V; V _{EB} = 0 | | 0.1 | mA |
| I _{CEO} | Collector Cutoff Current | V _{CE} = 40V; I _B = 0 | | 0.5 | mA |
| І _{ЕВО} | Emitter Cutoff Current | V _{EB} = 8V; I _C = 0 | | 10 | uA |
| h _{FE-1} | DC Current Gain | I _C = 0.1A; V _{CE} = 1V | 60 | | |
| h _{FE-2} | DC Current Gain | Ic= 2A; VcE= 1V | 20 | | |
| f⊤ | Current-Gain—Bandwidth Product | I _C = 0.1A; V _{CE} = 10V | 4 | | MHz |

NOTICE:

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